

850 EVO mSATA Solid State Drives

250 GB	MZ-M5E250BW
500 GB	MZ-M5E500BW
1 TB (1,000 GB)	MZ-M5E1T0BW

SAMSUNG

Improved speed and performance, ready to install



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The advanced consumer SSD in an mSATA form factor, powered by exclusive Samsung V-NAND technology.

- SATA 6Gb/s SSD for Client PCs
- mSATA
- Samsung V-NAND
- Samsung Magician Software for SSD management
- Samsung Data Migration Software

Key features



V-NAND technology in the Samsung 850 EVO mSATA SSD

Samsung's unique V-NAND flash memory architecture is a breakthrough in overcoming the density, performance and endurance limitations of today's conventional planar NAND architecture. V-NAND is fabricated by stacking cell layers vertically, rather than decreasing the cells' dimensions to fit into increasingly smaller form factors. The result is higher density and better performance with a smaller footprint.



Optimized performance for everyday computing

Powered by Samsung's cutting-edge V-NAND technology, the 850 EVO mSATA delivers top-class sequential and random read and write performance to optimize everyday computing. The 850 EVO mSATA seamlessly integrates V-NAND memory, a MGX controller, DRAM memory and Samsung Magician software for high optimization. Like the 2.5" form factor, the 850 EVO mSATA maximizes the user experience with a trace-based benchmark, giving you form factor flexibility for SATA 6Gb/s interfaces.



Reinforcement of TurboWrite technology

Samsung was the first to introduce TurboWrite technology to sequential write performance. With TurboWrite Technology, write speeds have been significantly accelerated during data transfer by creating a high-performance write buffer in an SSD. If a consecutive write operation (i.e. no idle time) exceeds the size of a buffer, the transfer will exit TurboWrite and be processed at "After TurboWrite" speeds. But since the buffer size is more than sufficient for everyday computer use, users experience accelerated speeds for most workloads.



Guaranteed endurance and reliability for maximum use

The 850 EVO mSATA Series delivers guaranteed endurance and reliability by doubling the TeraBytes Written (TBW) compared to the previous generation 840 EVO Series. The 850 EVO mSATA Series is backed by an industry-leading 5 year warranty or 75TBW (250 GB)/150TBW (500 GB, 1 TB). With twice the endurance of a typical NAND flash SSD, the 850 EVO mSATA Series will keep working as long as you do.



Enhanced reliability with improved sustained performance

The 850 EVO mSATA Series boasts dependable performance up to 40% longer than the 840 EVO Series, with minimized performance degradation. You can use it every day, knowing it will perform at the highest levels for years.



Advanced data encryption

Self-Encrypting Drive (SED) security technology helps keep your data safe. An AES 256-bit hardware-based encryption engine secures your data without any of the performance degradation you might experience with software-based encryption. The 850 EVO mSATA is compliant with advanced security management solutions (TCG Opal and IEEE 1667), and you can erase or initialize data with the PSID crypto erase service.



Efficient power management for all PC applications

Since V-NAND uses half the power of 2D planar NAND, you save up to 50% more power during write operations than with the 840 EVO Series. And with a highly efficient 2mW Device Sleep feature and a controller optimized for V-NAND, you get longer battery life.

Samsung 850 EVO mSATA
Solid State Drives



	MZ-M5E250BW	MZ-M5E500BW	MZ-M5E1T0BW
Usage Application	Client PCs	Client PCs	Client PCs
Capacity¹	250GB	500GB	1TB (1,000GB)
Dimensions (WxHxD)	(29.85±0.15) x (50.80±0.15) x Max 3.85 (mm) / 1.18" x 2.00" x 0.15"	(29.85±0.15) x (50.80±0.15) x Max 3.85 (mm) / 1.18" x 2.00" x 0.15"	(29.85±0.15) x (50.80±0.15) x Max 3.85 (mm) / 1.18" x 2.00" x 0.15"
Interface	SATA 6Gb/s (Compatible with SATA 3Gb/s and SATA 1.5Gb/s)	SATA 6Gb/s (Compatible with SATA 3Gb/s and SATA 1.5Gb/s)	SATA 6Gb/s (Compatible with SATA 3Gb/s and SATA 1.5Gb/s)
Form Factor	mSATA	mSATA	mSATA
Controller	Samsung MGX Controller	Samsung MGX Controller	Samsung MGX Controller
NAND Flash Memory	Samsung V-NAND Flash	Samsung V-NAND Flash	Samsung V-NAND Flash
DRAM Cache Memory	512MB LPDDR3	512MB LPDDR3	1GB LPDDR3
Performance²	Sequential Read (Max.):	540 MB/s	540 MB/s
	Sequential Write³ (Max.):	520 MB/s	520 MB/s
	4KB Random Read (QD1)(Max.):	10,000 IOPS	10,000 IOPS
	4KB Random Write (QD1)(Max.):	40,000 IOPS	40,000 IOPS
	4KB Random Read (QD32)(Max.):	97,000 IOPS	97,000 IOPS
	4KB Random Write (QD32)(Max.):	88,000 IOPS	88,000 IOPS
Data Security	AES 256-bit Full Disk Encryption (FDE) TCG/Opal V2.0, Encrypted Drive (IEEE1667)	AES 256-bit Full Disk Encryption (FDE) TCG/Opal V2.0, Encrypted Drive (IEEE1667)	AES 256-bit Full Disk Encryption (FDE) TCG/Opal V2.0, Encrypted Drive (IEEE1667)
Weight (Max.)	8.5g	8.5g	8.5g
Reliability (MTBF)	1.5 Million Hours	1.5 Million Hours	1.5 Million Hours
TBW (Terabytes Written)	75TBW	150TBW	150TBW
Power Consumption⁴	Active Read/Write (Average/Max):	2.3W / 2.7W	2.3W / 2.7W
	Idle (Max.):	50mW	50mW
	Device Sleep (Typ.):	2mW	3mW
Supporting Features	TRIM (Required OS Support), Garbage Collection, S.M.A.R.T	TRIM (Required OS Support), Garbage Collection, S.M.A.R.T	TRIM (Required OS Support), Garbage Collection, S.M.A.R.T
Temperature	Operating:	0°C to 70°C	0°C to 70°C
	Non-Operating:	-40°C to 85°C	-40°C to 85°C
Humidity	5% to 95%, Non-Condensing	5% to 95%, Non-Condensing	5% to 95%, Non-Condensing
Vibration (Non-Operating)	20~2000Hz, 20G	20~2000Hz, 20G	20~2000Hz, 20G
Shock (Non-Operating)	1500G, Duration 0.5m Sec, 3 Axis	1500G, Duration 0.5m Sec, 3 Axis	1500G, Duration 0.5m Sec, 3 Axis
Warranty	5 Years Limited	5 Years Limited	5 Years Limited

¹1GB = 1,000,000,000 bytes. Actual usable capacity may be less (due to formatting, partitioning, operating system, applications or otherwise).

²Sequential performance measurements based on CrystalDiskMark v.3.0.1. Random performance measurements based on Iometer 1.1.0. Performance may vary based on SSD's firmware version, system hardware and configuration. Test system configuration: Intel Core i7-4790K @ 4.0GHz, DDR3 1600MHz 8GB, OS: Windows 7 Ultimate x64 SP1, IRST 13.0.3.1001, Chipset: Intel® Z97PRO.

³Sequential Write performance measurements based on TurboWrite technology. The sequential write performances after TurboWrite region are 300MB/s (250GB) and 500MB/s (500GB).

⁴Power consumption measured with Iometer 1.1.0 with Intel i7-4770K, DDR3 8GB, Intel® DH87RL, OS: Windows 7 Ultimate x64 SP1.



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